Low-Power, Rail-to-Rail In/Out, 500-µV Typical Offset, 1-MHz Operational Amplifier for Cost-Sensitive Systems

Description

The TLV313 family of single-, dual-, and quad-channel precision operational amplifiers combine low power consumption with good performance. This makes them suitable for a wide range of applications, such as wearables, utility metering, building automation, currency counters and more. The family features rail-to-rail input and output (RRIO) swings, low quiescent current (65 µA, typical), wide bandwidth (1 MHz) and very low noise (26 nV/√Hz at 1 kHz), making it attractive for a variety of battery-powered applications that require a good balance between cost and performance. Further, low-input-bias current enables these devices to be used in applications with megaohm source impedances.

The robust design of the TLV313 devices provides ease-of-use to the circuit designer: unity-gain stability with capacitive loads of up to 150 pF, integrated RF/EMI rejection filter, no phase reversal in overdrive conditions, and high electrostatic discharge (ESD) protection (4-kV HBM).

The devices are optimized for operation at voltages as low as +1.8 V (±0.9 V) and up to +5.5 V (±2.75 V), and are specified over the extended temperature range of –40°C to +125°C.

The single-channel TLV313 device is available in both SC70-5 and SOT23-5 packages. The dual-channel TLV2313 device is offered in SOP-8 , and the quad-channel TLV4313 device is offered in a TSSOP-14 package.

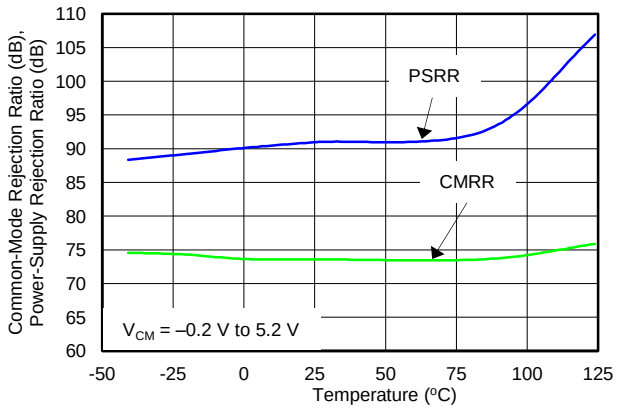
Features

- Precision Amplifier for Cost-Sensitive Systems
- Low I_Q: 65 µA/ch
- Wide Supply Range: 1.8 V to 5.5 V
- Low Noise: 26 nV/√Hz at 1 kHz
- Gain Bandwidth: 1 MHz
- Rail-to-Rail Input/Output
- Low Input Bias Current: 1 pA
- Low Offset Voltage: 0.75 mV
- Unity-Gain Stable
- Internal RF/EMI Filter
- Extended Temperature Range: –40°C to +125°C

Applications

- Medical and Healthcare
- Fitness and Wearable Electronics
- Utility Metering (Heat, Water, Energy)
- Building Automation Equipment
- Currency Counters

CMRR and PSRR vs Temperature

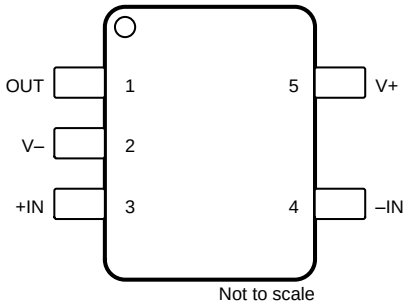


Device Comparison Table

	NO. OF	PACKAGE LEADS			
DEVICE	CHANNELS	SC70	SOT23	SOP	TSSOP
TLV313	1	5	5	—	—
TLV2313	2	—	—	8	—
TLV4313	4	—	—	—	14

Pin Configuration and Functions

DCK Package
5-Pin SC70
TLV313 Top View



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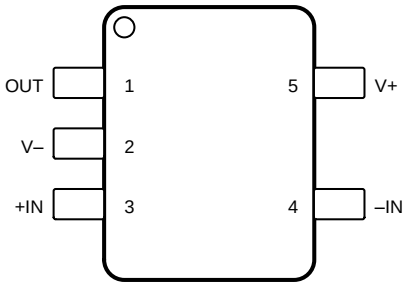
DBV Package
5-Pin SOT23
TLV313 Top View

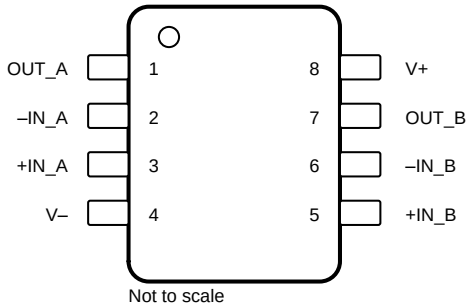


Not to scale

Pin Functions: TLV313

PIN			I/O	DESCRIPTION
NAME	DCK (SC70)	DBV (SOT23)		
+IN	3	3	I	Inverting input
V–	2	2	—	Negative (lowest) power supply
–IN	4	4	I	Noninverting input
OUT	1	1	O	Output
V+	5	5	—	Positive (highest) power supply

D, DGK Packages
8-Pin SOP, TLV2313 Top View

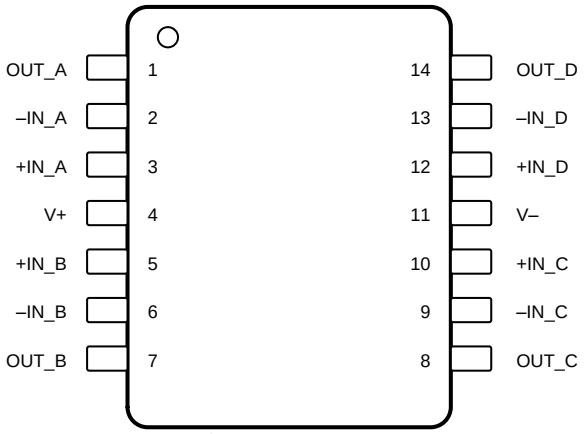


Not to scale

Pin Functions: TLV2313

PIN		I/O	DESCRIPTION
NAME	D (SOP)		
V–	4	—	Negative (lowest) power supply
V+	8	—	Positive (highest) power supply
OUT A	1	O	Output, channel A
OUT B	7	O	Output, channel B
–IN A	2	I	Inverting input, channel A
+IN A	3	I	Noninverting input, channel A
–IN B	6	I	Inverting input, channel B
+IN B	5	I	Noninverting input, channel B

PW Package
14-Pin TSSOP
TLV4313 Top View



Not to scale

Pin Functions: TLV4313

PIN		I/O	DESCRIPTION
NAME	PW (TSSOP)		
V–	11	—	Negative (lowest) power supply
V+	4	—	Positive (highest) power supply
OUT A	1	O	Output, channel A
OUT B	7	O	Output, channel B
OUT C	8	O	Output, channel C
OUT D	14	O	Output, channel D
–IN A	2	I	Inverting input, channel A
+IN A	3	I	Noninverting input, channel A
–IN B	6	I	Inverting input, channel B
+IN B	5	I	Noninverting input, channel B
–IN C	9	I	Inverting input, channel C
+IN C	10	I	Noninverting input, channel C
–IN D	13	I	Inverting input, channel D
+IN D	12	I	Noninverting input, channel D

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Voltage	Supply voltage		7	V
	Signal input terminals(2)	(V−) − (0.5)	(V+) + 0.5	V
Current	Signal input terminals(2)	–10	10	mA
	Output short circuit(3)	Continuous		
Temperature	Operating, T_A	–40	150	°C
	Junction, T_J		150	°C
	Storage, T_{stg}	–65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.
(3) Short-circuit to ground, one amplifier per package.

ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±4000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_S	Supply voltage	1.8	5.5	V
T_A	Specified temperature range	–40	125	°C

ThermalInformation: TLV313

THERMAL METRIC(1)		TLV313		UNIT
		DBV (SOT23)	DCK (SC70)	
		5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	228.5	281.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	99.1	91.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	54.6	59.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	7.7	1.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	53.8	58.8	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

ThermalInformation: TLV2313

THERMAL METRIC(1)		TLV2313		UNIT
		D (SOIC)	DGK (VSSOP)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	138.4	191.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	89.5	61.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	78.6	111.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	29.9	5.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	78.1	110.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

ThermalInformation: TLV4313

THERMAL METRIC(1)		TLV4313	UNIT
		PW (TSSOP)	
		14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	121.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	49.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	62.8	°C/W
ψ_{JT}	Junction-to-top characterization parameter	5.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	62.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

Electrical Characteristics5.5 V(1)

At T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, and V_{CM} = V_{OUT} = V_S / 2, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET VOLTAGE						
V_{OS}	Input offset voltage			0.75	3	mV
dV_{OS}/dT	Input offset voltage vs temperature	T_A = –40°C to 125°C		2		µV/°C
PSRR	Power-supply rejection ratio		74	90		dB
INPUT VOLTAGE RANGE						
V_{CM}	Common-mode voltage range	No phase reversal, rail-to-rail input	(V–) – 0.2		(V+) + 0.2	V
CMRR	Common-mode rejection ratio	(V_S–) – 0.2 V < V_{CM} < (V_S+) – 1.3 V		85		dB
		V_{CM} = –0.2 V to 5.7 V	64	80		dB
INPUT BIAS CURRENT						
I_B	Input bias current			±1		pA
I_{OS}	Input offset current			±1		pA
NOISE						
	Input voltage noise (peak-to-peak)	f = 0.1 Hz to 10 Hz		6		μV_{PP}
e_n	Input voltage noise density	f = 10 kHz		22		nV/√Hz
		f = 1 kHz		26		nV/√Hz
i_n	Input current noise density	f = 1 kHz		5		fA/√Hz
INPUT CAPACITANCE						
C_{IN}	Differential			1		pF
	Common-mode			5		pF
OPEN-LOOP GAIN						
A_{OL}	Open-loop voltage gain	0.05 V < V_O < (V+) – 0.05 V, R_L = 100 kΩ		104		dB
		0.3 V < V_O < (V+) – 0.3 V, R_L = 2 kΩ	100	110		dB
	Phase margin	V_S = 5.0 V, G = +1		65		°

(1) Parameters with minimum or maximum specification limits are 100% production tested at 25ºC, unless otherwise noted. Over-temperature limits are based on characterization and statistical analysis.

Electrical Characteristics5.5 V(1)

At T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, and V_{CM} = V_{OUT} = V_S / 2, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
FREQUENCY RESPONSE						
GBW	Gain-bandwidth product	V_S = 5.0 V, C_L = 10 pF		1		MHz
SR	Slew rate	V_S = 5.0 V, G = +1		0.5		V/µs
t_S	Settling time	To 0.01%, V_S = 5.0 V, 2-V step , G = +1		6		µs
	Overload recovery time	V_S = 5.0 V, V_{IN} × Gain > V_S		3		µs
OUTPUT						
V_O	Voltage output swing from supply rails	R_L = 100 kΩ(2)		5	20	mV
		R_L = 2 kΩ(2)		75	100	mV
I_{SC}	Short-circuit current			±15		mA
R_O	Open-loop output impedance			2300		Ω
POWER SUPPLY						
V_S	Specified voltage range		1.8 (±0.9)		5.5 (±2.75)	V
I_Q	Quiescent current per amplifier	T_A = –40°C to 125°C, V_S = 5.0 V, I_O = 0 mA		65	90	µA
	Power-on time	V_S = 0 V to 5 V, to 90% I_Q level		10		µs
TEMPERATURE						
	Specified range		–40		125	°C
	Operating range		–40		150	°C
T_{stg}	Storage range		–65		150	°C

(2) Specified by design and characterization; not production tested.

Electrical Characteristics: 1.8 V(1)

At T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_{S+} – 1.3 V, and V_{OUT} = V_S / 2, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET VOLTAGE						
V_{OS}	Input offset voltage			0.75	3	mV
dV_{OS}/dT	Input offset voltage vs temperature	T_A = –40°C to 125°C		2		µV/°C
PSRR	Power-supply rejection ratio		74	90		dB
INPUT VOLTAGE RANGE						
V_{CM}	Common-mode voltage range	No phase reversal, rail-to-rail input	(V–) – 0.2		(V+) + 0.2	V
CMRR	Common-mode rejection ratio	(V_S–) – 0.2 V < V_{CM} < (V_S+) – 1.3 V		85		dB
		V_{CM} = –0.2 V to +1.8 V		73		dB
INPUT BIAS CURRENT						
I_B	Input bias current			±1		pA
I_{OS}	Input offset current			±1		pA
NOISE						
	Input voltage noise (peak-to-peak)	f = 0.1 Hz to 10 Hz		6		μV_{PP}
e_n	Input voltage noise density	f = 10 kHz		22		$nV/\sqrt{Hz}$
		f = 1 kHz		26		$nV/\sqrt{Hz}$
i_n	Input current noise density	f = 1 kHz		5		$fA/\sqrt{Hz}$
INPUT CAPACITANCE						
C_{IN}	Differential			1		pF
	Common-mode			5		pF
OPEN-LOOP GAIN						
A_{OL}	Open-loop voltage gain	0.1 V < V_O < (V+) – 0.1 V, R_L = 10 kΩ		110		dB
		0.05 V < V_O < (V+) – 0.05 V, R_L = 100 kΩ		110		dB

(1) Parameters with minimum or maximum specification limits are 100% production tested at 25ºC, unless otherwise noted. Over-temperature limits are based on characterization and statistical analysis.

Electrical Characteristics: 1.8 V(1)

At T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_{S+} – 1.3 V, and V_{OUT} = V_S / 2, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
FREQUENCY RESPONSE						
GBW	Gain-bandwidth product	C_L = 10 pF		0.9		MHz
SR	Slew rate	G = +1		0.45		V/µs
t_S	Settling time	To 0.01%, V_S = 5.0 V, 2-V step , G = +1		6		µs
	Overload recovery time	V_S = 5.0 V, V_{IN} × Gain > V_S		3		µs
OUTPUT						
V_O	Voltage output swing from supply rails	R_L = 100 kΩ(2)		5		mV
		R_L = 2 kΩ(2)		25		mV
I_{SC}	Short-circuit current			±6		mA
R_O	Open-loop output impedance			2300		Ω
POWER SUPPLY						
V_S	Specified voltage range		1.8 (±0.9)		5.5 (±2.75)	V
I_Q	Quiescent current per amplifier	T_A = –40°C to 125°C, V_S = 5.0 V, I_O = 0 mA		65	90	µA
	Power-on time	V_S = 0 V to 5 V, to 90% I_Q level		10		µs
TEMPERATURE						
	Specified range		–40		125	°C
	Operating range		–40		150	°C
T_{stg}	Storage range		–65		150	°C

(2) Specified by design and characterization; not production tested.

Typical Characteristics

At T_A = 25°C, V_S = 5 V, R_L = 10 kΩ connected to V_S / 2, and V_{CM} = V_{OUT} = V_S / 2, unless otherwise noted.

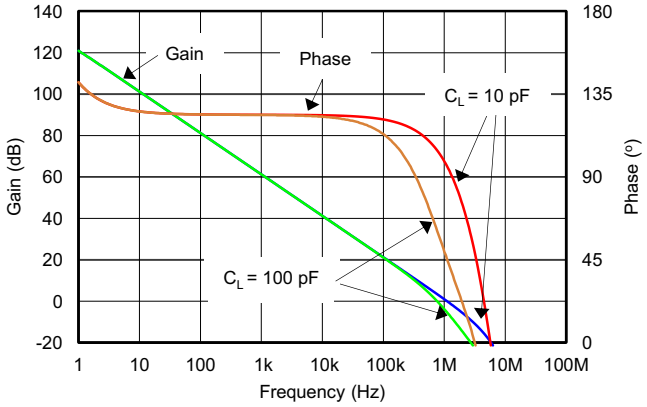


Figure 1. Open-Loop Gain and Phase vs Frequency

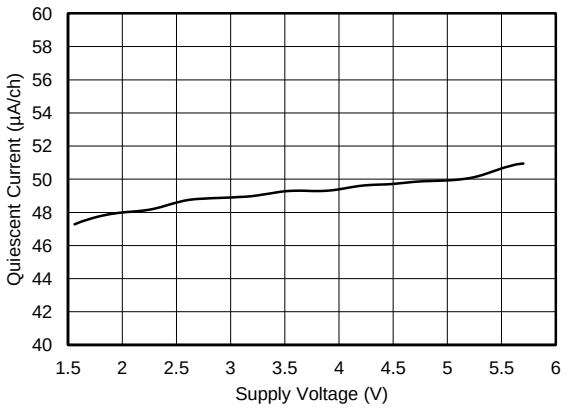


Figure 2. Quiescent Current vs Supply

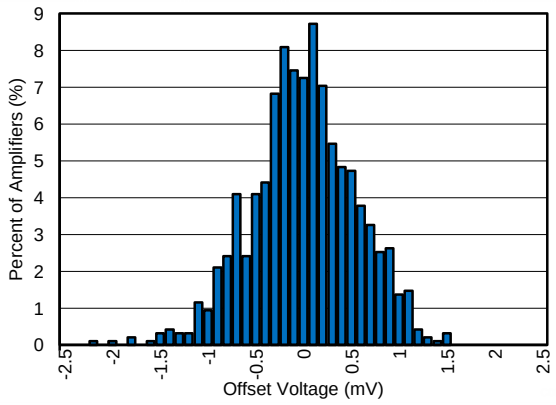


Figure 3. Offset Voltage Production Distribution

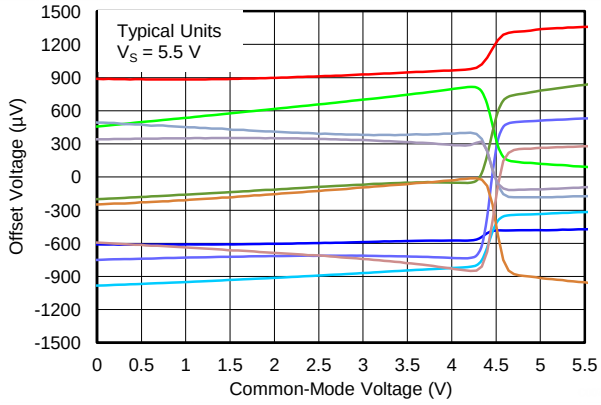


Figure 4. Offset Voltage vs Common-Mode Voltage

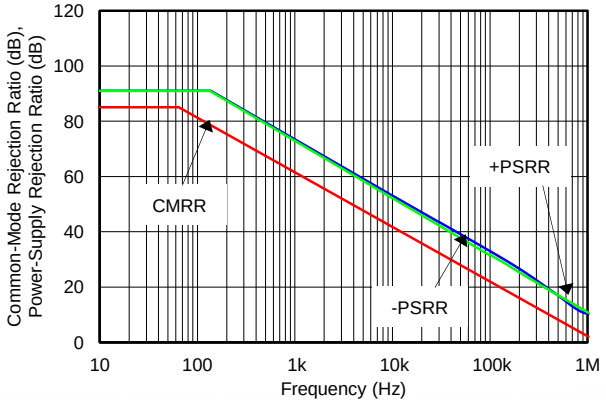


Figure 5. CMRR and PSRR vs Frequency (Referred-to-Input)

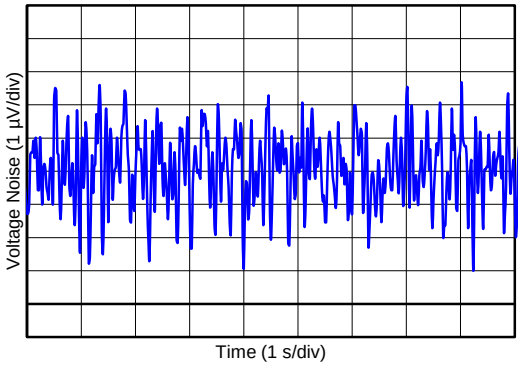


Figure 6. 0.1-Hz to 10-Hz Input Voltage Noise

Typical Characteristics

At T_A = 25°C, V_S = 5 V, R_L = 10 kΩ connected to V_S / 2, and V_{CM} = V_{OUT} = V_S / 2, unless otherwise noted.

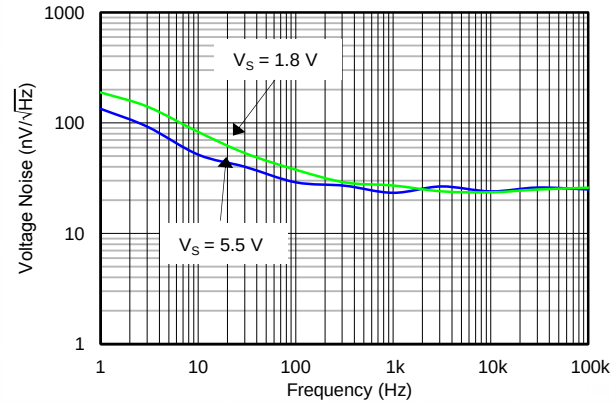


Figure 7. Input Voltage Noise Spectral Density vs Frequency

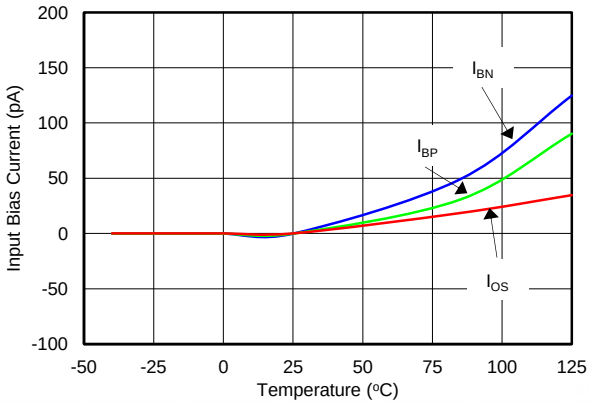


Figure 8. Input Bias and Offset Current vs Temperature

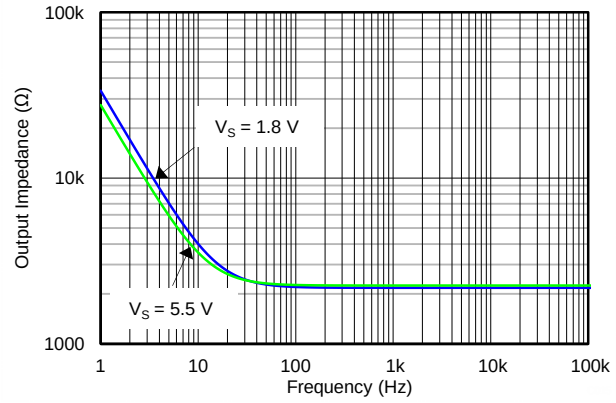


Figure 9. Open-Loop Output Impedance vs Frequency

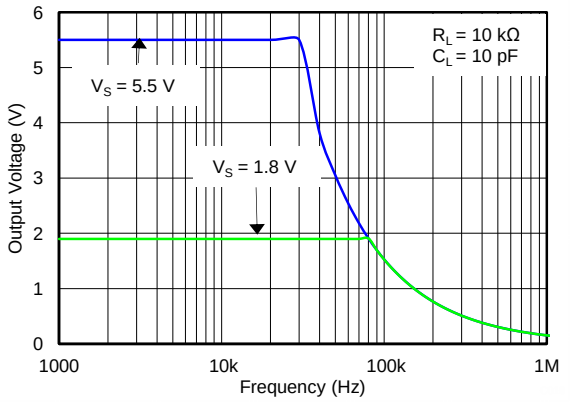


Figure 10. Maximum Output Voltage vs Frequency and Supply Voltage

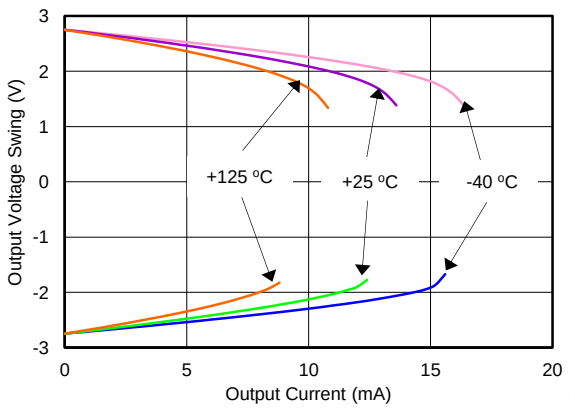


Figure 11. Output Voltage Swing vs Output Current (Over Temperature)

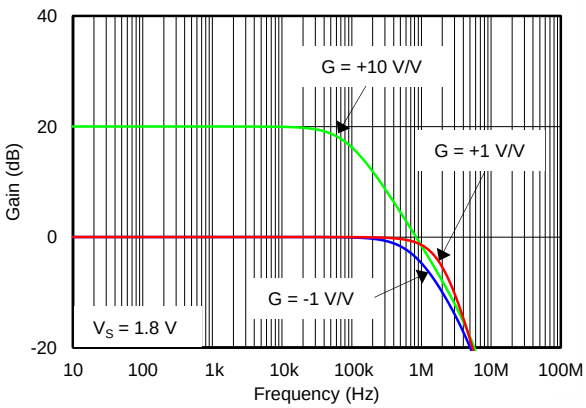


Figure 12. Closed-Loop Gain vs Frequency (Minimum Supply)

Typical Characteristics

At T_A = 25°C, V_S = 5 V, R_L = 10 kΩ connected to V_S / 2, and V_{CM} = V_{OUT} = V_S / 2, unless otherwise noted.

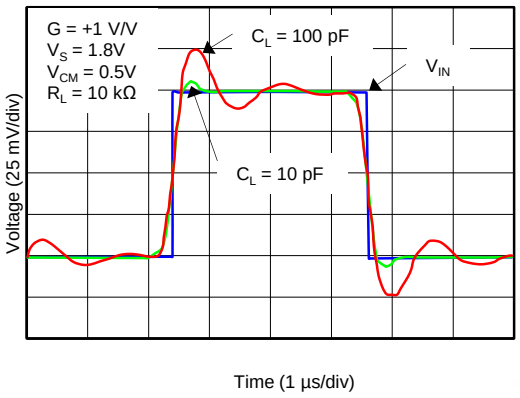


Figure 13. Small-Signal Pulse Response (Minimum Supply)

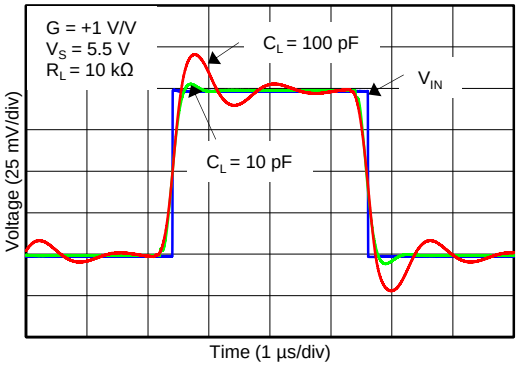


Figure 14. Small-Signal Pulse Response (Maximum Supply)

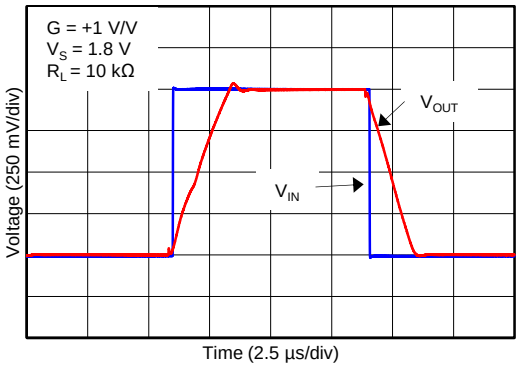


Figure 15. Large-Signal Pulse Response (Minimum Supply)

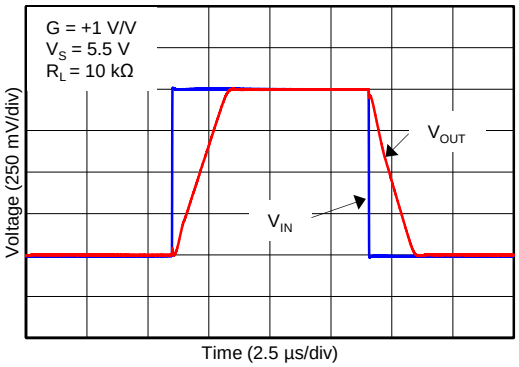


Figure 16. Large-Signal Pulse Response (Maximum Supply)

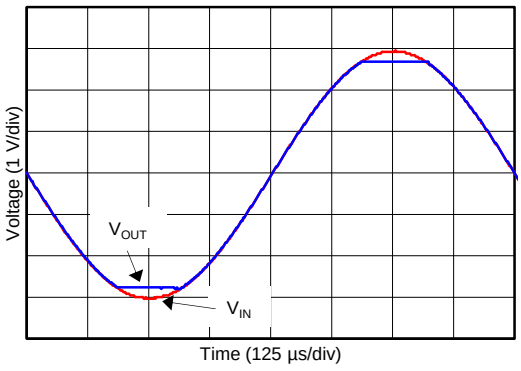


Figure 17. No Phase Reversal

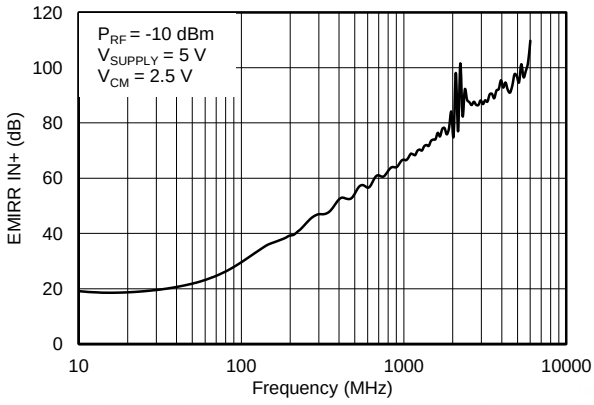
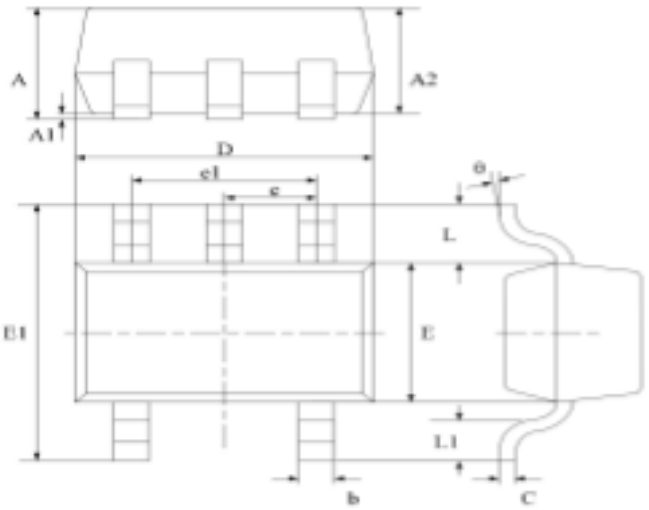


Figure 18. EMIRR IN+ vs Frequency

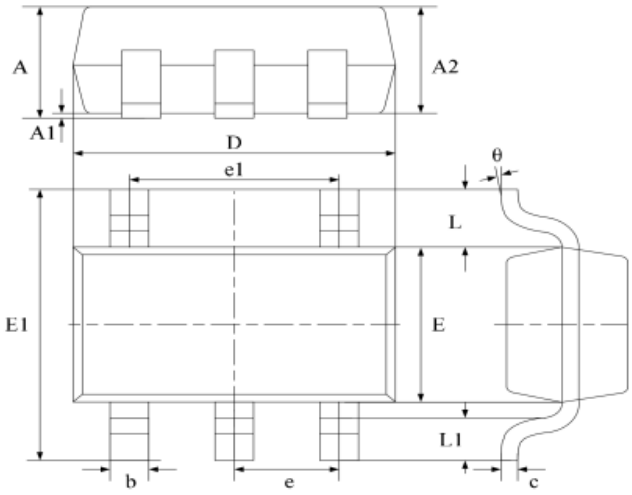
Package Dimension

SC70-5（SOT353）



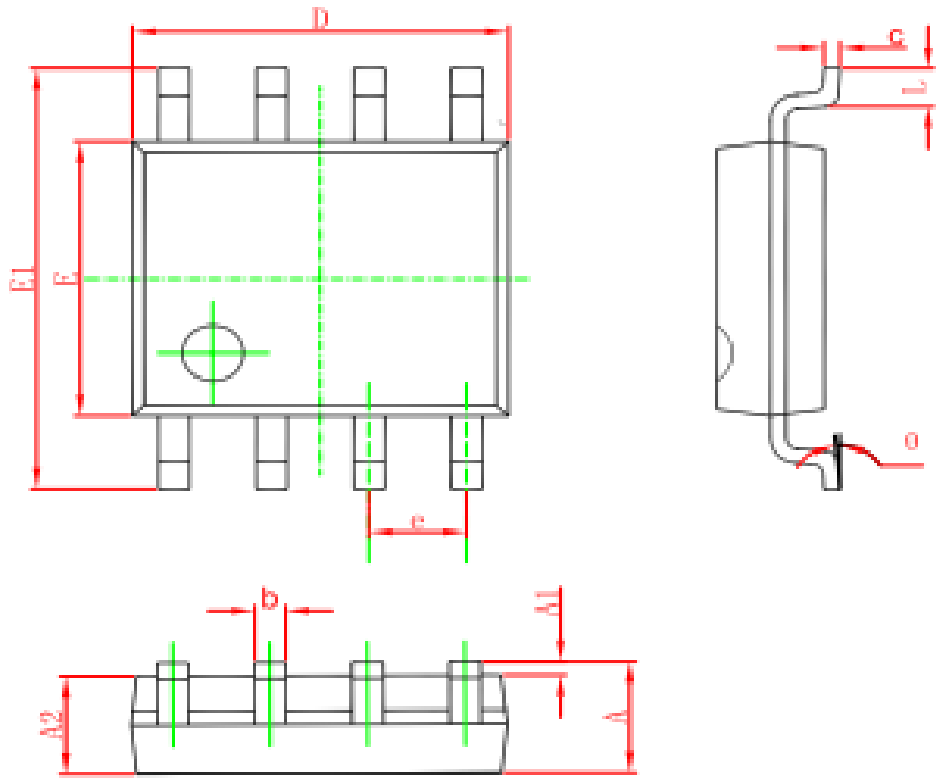
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.800	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.035	0.039
b	0.150	0.350	0.006	0.014
C	0.080	0.150	0.003	0.006
D	1.8500	2.150	0.079	0.087
E	1.100	1.400	0.045	0.053
E1	1.950	2.200	0.085	0.096
e	0.850 typ.		0.026 typ.	
e1	1.200	1.400	0.047	0.055
L	0.42 ref.		0.021 ref.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT23-5



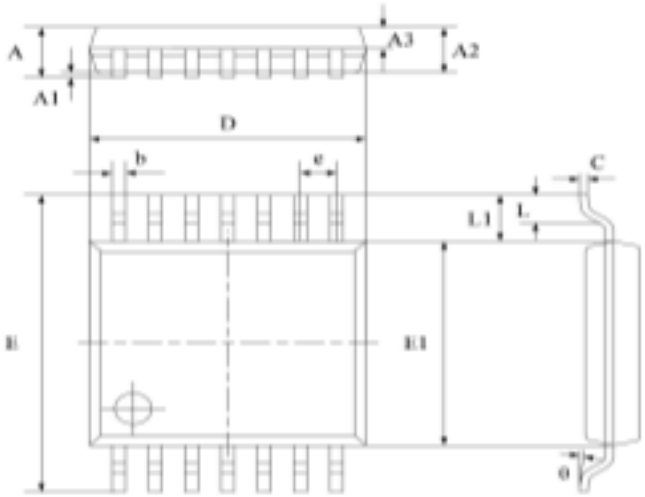
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.040	1.350	0.042	0.055
A1	0.040	0.150	0.002	0.006
A2	1.000	1.200	0.041	0.049
b	0.380	0.480	0.015	0.020
c	0.110	0.210	0.004	0.009
D	2.720	3.120	0.111	0.127
E	1.400	1.800	0.057	0.073
E1	2.600	3.000	0.106	0.122
e	0.950 typ.		0.037 typ.	
e1	1.900 typ.		0.078 typ.	
L	0.700 ref.		0.028 ref.	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

TSSOP-14



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	-	1.200	-	0.0472
A1	0.050	0.150	0.002	0.006
A2	0.900	1.050	0.037	0.043
A3	0.390	0.490	0.016	0.020
b	0.200	0.290	0.008	0.012
C	0.130	0.180	0.005	0.007
D	4.860	5.060	0.198	0.207
E	6.200	6.600	0.253	0.269
E1	4.300	4.500	0.176	0.184
e	0.650 typ.		0.0256 typ.	
L1	1.000 ref.		0.0393 ref.	
L	0.450	0.750	0.018	0.031
θ	0°	8°	0°	8°

Order code	Package	Baseqty	Deliverymode	Marking
UMW TLV313IDCKR	SC70-5	3000	Tape and reel	14E U
UMW TLV313IDBVR	SOT23-5	3000	Tape and reel	15F2 U
UMW TLV2313IDR	SOP-8	2500	Tape and reel	V2313
UMW TLV4313IPWR	TSSOP-14	4000	Tape and reel	TLV4313